

# Advanced Monolithic Systems

## AMS682 INVERTING VOLTAGE DOUBLER

### FEATURES

- 99.9% Voltage Conversion Efficiency
- 92% Power Conversion Efficiency
- Wide Input Voltage Range +2.4V to 5.5V
- 185 $\mu$ A Supply Current
- Available in SO-8 and PDIP Packages
- Only 3 external Capacitors Required

### APPLICATIONS

- Portable Handheld Instrumentation
- Cellular Phones
- Panel Meters
- -10V from +5V logic Supply
- -6V from a Single 3V Lithium Cell
- LCD Display Bias Generator
- Operational Amplifiers Power Supplies

### GENERAL DESCRIPTION

The AMS682 is a CMOS charge pump converter that provides an inverted doubled output from a single positive supply. Requiring only three external capacitors for full circuit implementation the device has an on-board 12kHz (typical) oscillator which provides the clock.

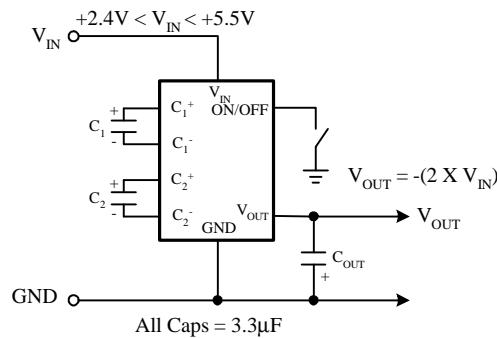
Low output source impedance (typically 140 $\Omega$ ), provides output current up to 10mA. The AMS682 features low quiescent current and high efficiency, making it the ideal choice for a wide variety of applications that require a negative voltage derived from a single positive supply. The compact size and minimum external parts count of the AMS682 makes it useful in many medium current, dual voltage analog power supplies.

The AMS682E is operational in the full industrial temperature range of -40°C to 85°C while AMS682C is operating over a 0°C to 70°C temperature range. The AMS682E/AMS682C are available in surface mount 8-Pin SOIC (SO-8) and 8-Pin Plastic DIP (PDIP) packages.

### ORDERING INFORMATION:

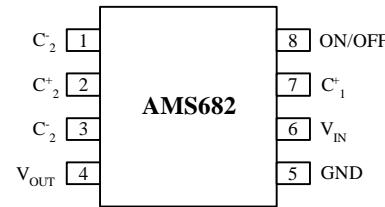
PACKAGE TYPE		OPERATING TEMPERATURE RANGE
8 LEAD SOIC	8 LEAD PDIP	
AMS682ES	AMS682EP	-40 to 85° C
AMS682CS	AMS682CP	0 to 70° C

### TYPICAL OPERATING CIRCUIT



### PIN CONFIGURATIONS

#### 8-LEAD DIP/ 8-LEAD SOIC



## ABSOLUTE MAXIMUM RATINGS

$V_{IN}$	+5.8V	Operating Temperature Range	
$V_{IN} \Delta V/\Delta T$	1V/ $\mu$ sec	AMS682E	-40°C to 85°C
$V_{OUT}$	-11.6V	AMS682C	0°C to 70°C
$V_{OUT}$ Short Circuit Duration	Continuous	Storage temperature	-85°C to +150°C
Power Dissipation ( $T_A = 70^\circ C$ )		Soldering information	
Plastic DIP	730mW	Lead Temperature (Soldering 10sec)	+300°C
SOIC	470mW		

## ELECTRICAL CHARACTERISTICS

Electrical Characteristics at  $V_{IN} = +5V$  and  $T_A = +25^\circ C$  test circuit figure 1, unless otherwise specified.

Parameter	Conditions	AMS682			Units
		Min	Typ	Max	
Supply Voltage Range	$V_{IN}$	2.4	—	5.5	V
Supply Current	$I_{IN}$	—	185	300	$\mu$ A
$R_{OUT}$	$R_L = \infty$	—	—	400	
$V_{OUT}$ Source Resistance	$R_{OUT}$	$I_L = 10mA$	140	180	$\Omega$
Source Resistance		$I_L = 10mA$	170	230	
		$I_L = 5mA, V_{IN} = 2.8V$	—	320	
Oscillator Frequency	$F_{OSC}$	—	12	—	kHz
Power Efficiency	$P_{EFF}$	$R_L = 2k\Omega$	90	92	%
Voltage Conversion Efficiency	$V_{OUT}E_{FF}$	$V_{OUT} R_L = \infty$	99	99.9	%

## PIN DESCRIPTION

PIN NO	8-PIN DIP/SOIC	SYMBOL	DESCRIPTION
1		$C_1^-$	Input. Capacitor $C_1$ negative terminal.
2		$C_2^+$	Input. Capacitor $C_2$ positive terminal.
3		$C_2^-$	Input. Capacitor $C_2$ negative terminal
4		$V_{OUT}$	Output. Negative output voltage (- $2V_{IN}$ )
5		GND	Input. Device ground.
6		$V_{IN}$	Input. Power supply voltage.
7		$C_1^+$	Input. Capacitor $C_1$ positive terminal.
8		ON/OFF	ON/OFF Oscilator.

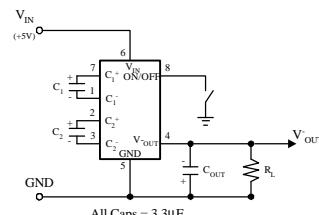


Figure 1. AMS682 Test Circuit

## DETAILED DESCRIPTION

### Phase 1

$V_{SS}$  charge storage- before this phase of the clock cycle, capacitor  $C_1$  is already charged to +5V.  $C_1^+$  is then switched to ground and the charge in  $C_1^-$  is transferred to  $C_2$ . Since  $C_2^+$  is at +5V, the voltage potential across capacitor  $C_2$  is now -10V.

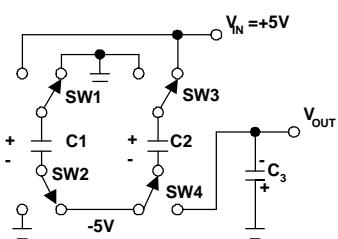


Figure 2. Charge Pump - Phase 1

### Phase 2

$V_{SS}$  transfer- phase two of the clock connects the negative terminal of  $C_2$  to the negative side of reservoir capacitor  $C_3$  and the positive terminal of  $C_2$  to the ground, transferring the generated -10V to  $C_3$ . Simultaneously, the positive side of capacitor  $C_1$  is switched to +5V and the negative side is connected to ground.  $C_2$  is then switched to  $V_{CC}$  and GND and Phase 1 begins again.

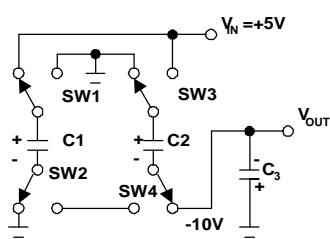


Figure 3. Charge Pump - Phase 2

## MAXIMUM OPERATING LIMITS

The AMS682 has on-chip zener diodes that clamp  $V_{IN}$  to approximately 5.8V, and  $V_{OUT}$  to -11.6V. Exceeding the maximum supply voltage will potentially damage the chip. With an input voltage of 2V to 5.5V the AMS682 will operate over the entire operating temperature range.

## EFFICIENCY CONSIDERATIONS

Theoretically a charge pump voltage multiplier can approach 100% efficiency under the following conditions:

- The charge pump switches have virtually no offset and are extremely low on resistance.
- Minimal power is consumed by the drive circuitry.
- The Impedances of the reservoir and pump capacitors are negligible.

For the AMS682, efficiency is as shown below:

$$\text{Voltage Efficiency} = V_{OUT} / (-2V_{IN})$$

$$V_{OUT} = -2V_{IN} + V_{DROP}$$

$$V_{DROP} = (I_{OUT}) (R_{OUT})$$

$$\text{Power Loss} = I_{OUT} (V_{DROP})$$

There will be a substantial voltage difference between  $V_{OUT}$  and  $2V_{IN}$  if the impedances of the pump capacitors  $C_1$  and  $C_2$  are high with respect to their respective output loads.

If the values of the reservoir capacitor  $C_3$  are larger the output ripple will be reduced. The efficiency will be improved if both pump and reservoir capacitors have larger values. ( See "Capacitor Selection" in Application Section.)

## APPLICATIONS

### Negative Doubling Converter

The AMS682 is most commonly used as a charge pump voltage converter which provides a negative output of two times a positive input voltage (Fig.4)

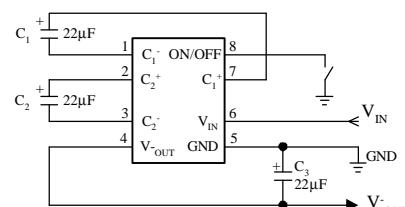


Figure 4. Inverting Voltage Doubler

**APPLICATIONS** (Continued)**Capacitor Selection**

The output resistance of the AMS682 is determined in part by the ESR of the capacitors used. An expression for  $R_{OUT}$  is derived as shown below:

$$R_{OUT} = 2(R_{SW1} + R_{SW2} + ESR_{C1} + R_{SW3} + R_{SW4} + ESR_{C2}) \\ + 2(R_{SW1} + R_{SW2} + ESR_{C1} + R_{SW3} + R_{SW4} + ESR_{C2}) \\ + 1/(f_{PUMP} \times C1) + 1/(f_{PUMP} \times C2) + ESR_{C3}$$

Assuming all switch resistances are approximately equal:

$$R_{OUT} = 16 R_{SW} + 4ESR_{C1} + 4ESR_{C2} + ESR_{C3} \\ + 1/(f_{PUMP} \times C1) + 1/(f_{PUMP} \times C2)$$

$R_{OUT}$  is typically  $140\Omega$  at  $+25^\circ C$  with  $V_{IN} = +5V$  and  $3.3\mu F$  low ESR capacitors. The fixed term ( $16R_{SW}$ ) is about  $80-90\Omega$ . Increasing or decreasing values of  $C1$  and  $C2$  will affect efficiency by changing  $R_{OUT}$ .

Table 1 shows  $R_{OUT}$  for various values of  $C1$  and  $C2$  (assume  $0.5\Omega$  ESR).  $C1$  must be rated at  $6VDC$  or greater while  $C2$  and  $C3$  must be rated at  $12VDC$  or greater.

Output voltage ripple is affected by  $C3$ . Typically the larger the value of  $C3$  the less the ripple for a given load current. The formula for p-p  $V_{RIPPLE}$  is :

$$V_{RIPPLE} = [1/(2(f_{PUMP} \times C3))] + 2(ESR_{C3}) (I_{OUT})$$

For a  $10\mu F$  ( $0.5\Omega$  ESR),  $f_{PUMP} = 10kHz$  and  $I_{OUT}=10mA$  the peak -to-peak ripple voltage at the output will be less than  $60mV$ . In most applications ( $I_{OUT} \leq 10mA$ ) a  $10-20\mu F$  capacitor and  $1-5\mu F$  pump capacitors will be sufficient. Table 2 shows  $V_{RIPPLE}$  for different values of  $C3$  (assume  $1\Omega$  ESR).

**Table 1.  $R_{OUT}$  vs.  $C1$ ,  $C2$** 

$C1$ , $C2$ ( $\mu F$ )	$R_{OUT}$ ( $\Omega$ )
0.05	4085
0.10	2084
0.47	510
1.00	285
3.30	145
5.00	125
10.00	105
22.00	94
100.00	87

**Paralleling devices**

Paralleling multiple AMS682 reduces the output resistance of the converter. The effective output resistance is the output resistance of one device divided by the number of devices. Figure 5 illustrates how each device requires separate pump capacitors  $C1$  and  $C2$ , but all can share a single reservoir capacitor.

**-5V Regulated Supply From A Single 3V Battery**

Figure 6 shows a -5V power supply using one 3V battery. The AMS682 provides -6V at  $V_{OUT}$ , which is regulated to -5V by the negative LDO. The AMS682 input can vary from 3V to 5.5V without affecting regulation significantly. A voltage detector is connected to the battery to detect undervoltage. This unit is set to detect at 2.7V. With higher input voltage, more current can be drawn from the outputs of the AMS682. With 5V at  $V_{IN}$ , 10mA can be drawn from the regulated output. Assuming  $150\Omega$  source resistance for the converter, with  $I_L=10mA$ , the charge pump will drop 1.5V.

**Table 2.  $V_{RIPPLE}$  Peak-to-Peak vs.  $C3$  ( $I_{OUT} = 10mA$ )**

$C3(\mu F)$	$V_{RIPPLE}$ (mV)
0.50	1020
1.00	520
3.30	172
5.00	120
10.00	70
22.00	43
100.00	25

## APPLICATIONS (Continued)

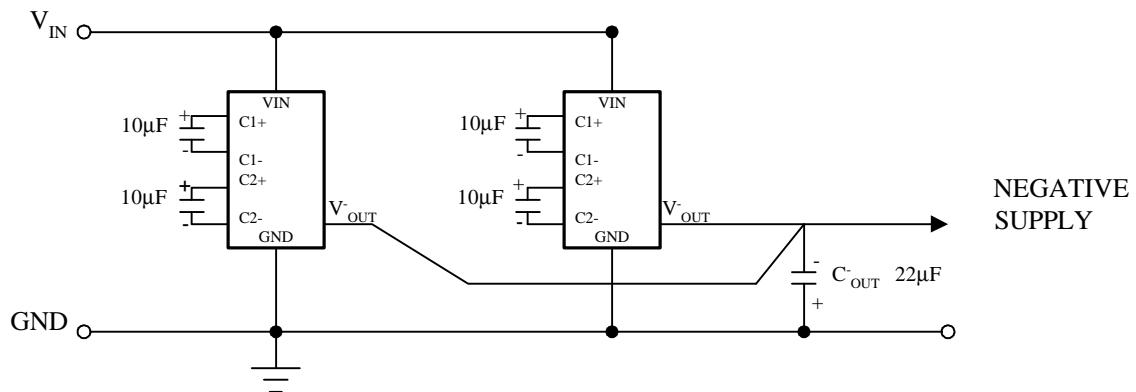


Figure 5. Paralleling AMS682 for Lower Output Source Resistance

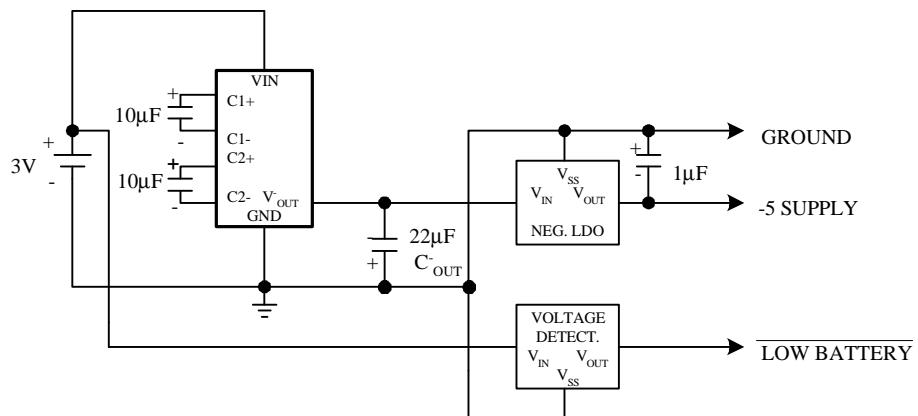
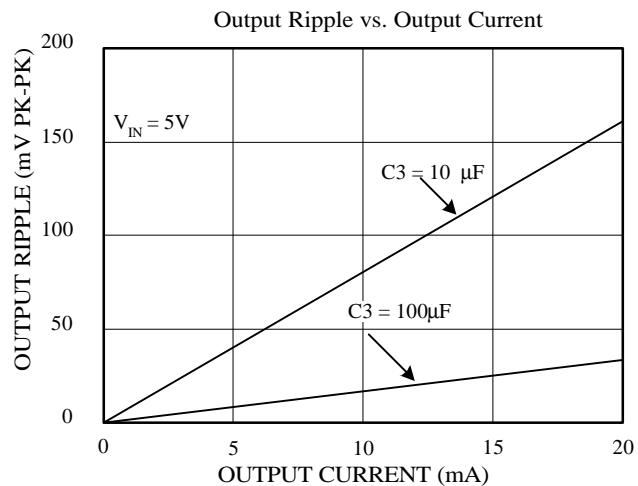
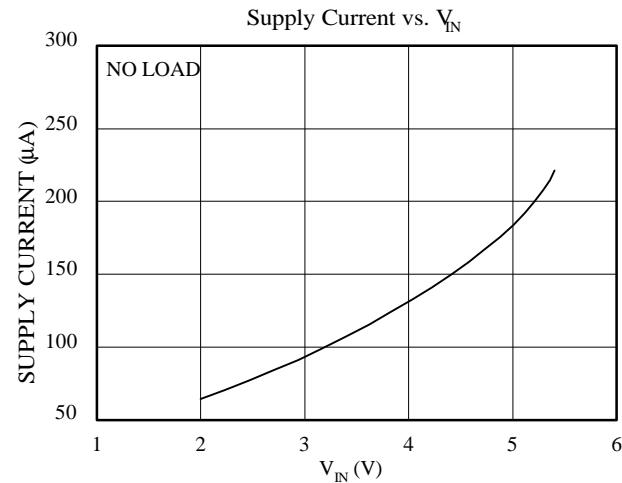
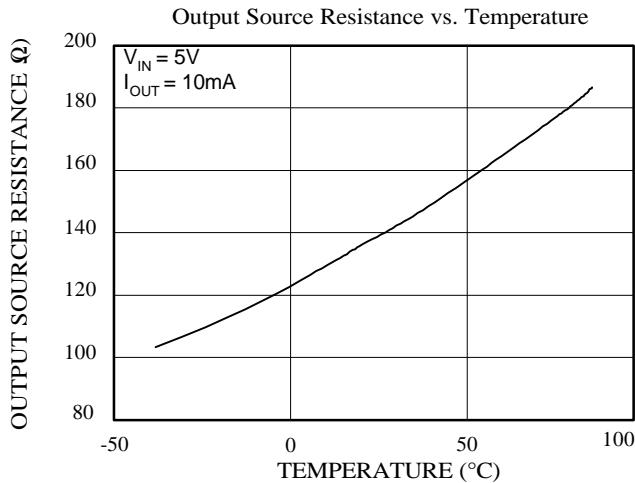
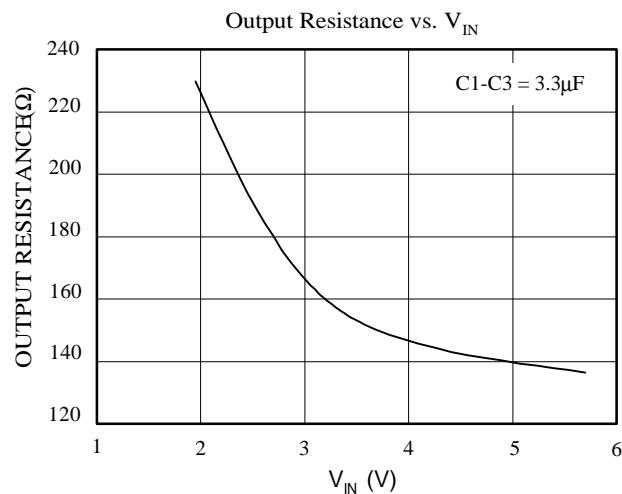
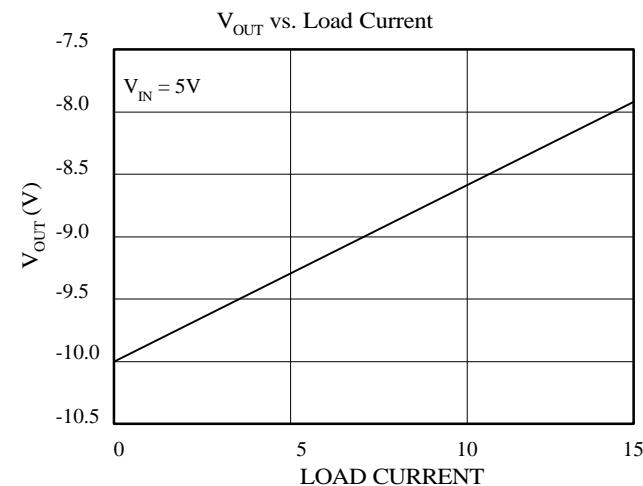


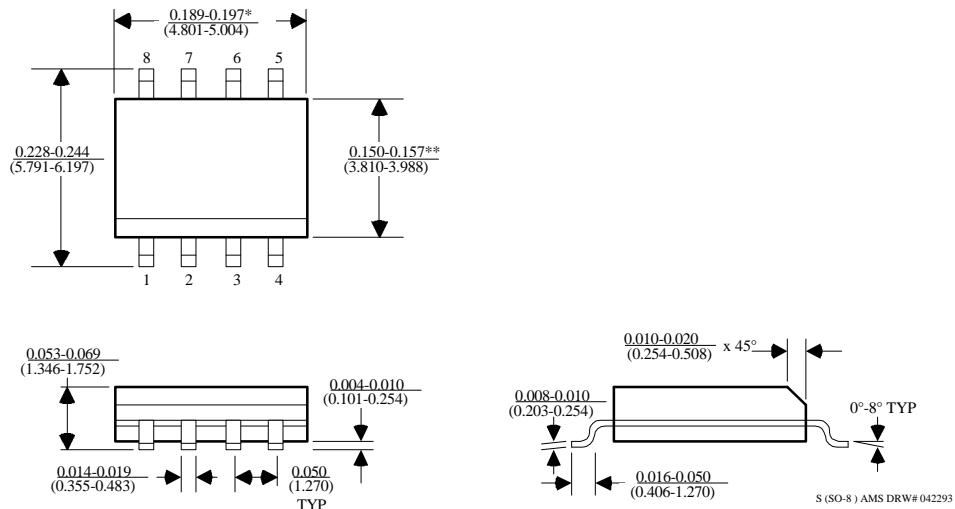
Figure 6. Negative Supply Derived from 3V Battery

## TYPICAL PERFORMANCE CHARACTERISTICS (F<sub>OSC</sub> = 12kHz)



## PACKAGE DIMENSIONS inches (millimeters) unless otherwise noted.

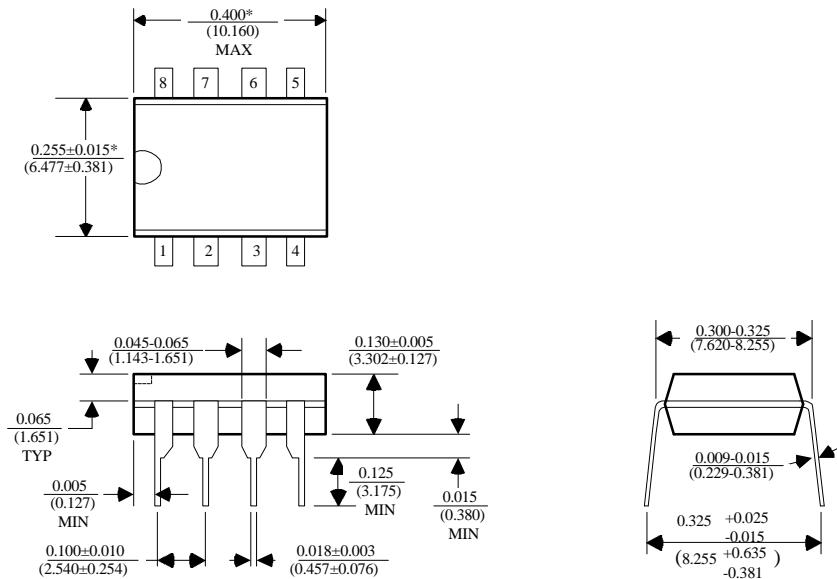
## 8 LEAD SOIC PLASTIC PACKAGE (S)



\*DIMENSION DOES NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE

\*\*DIMENSION DOES NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED 0.010" (0.254mm) PER SIDE

## 8 LEAD PLASTIC DIP PACKAGE (P)



\*DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTUSIONS.  
MOLD FLASH OR PROTUSIONS SHALL NOT EXCEED 0.010" (0.254mm)

P (8L PDIP ) AMS DRW# 042294

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